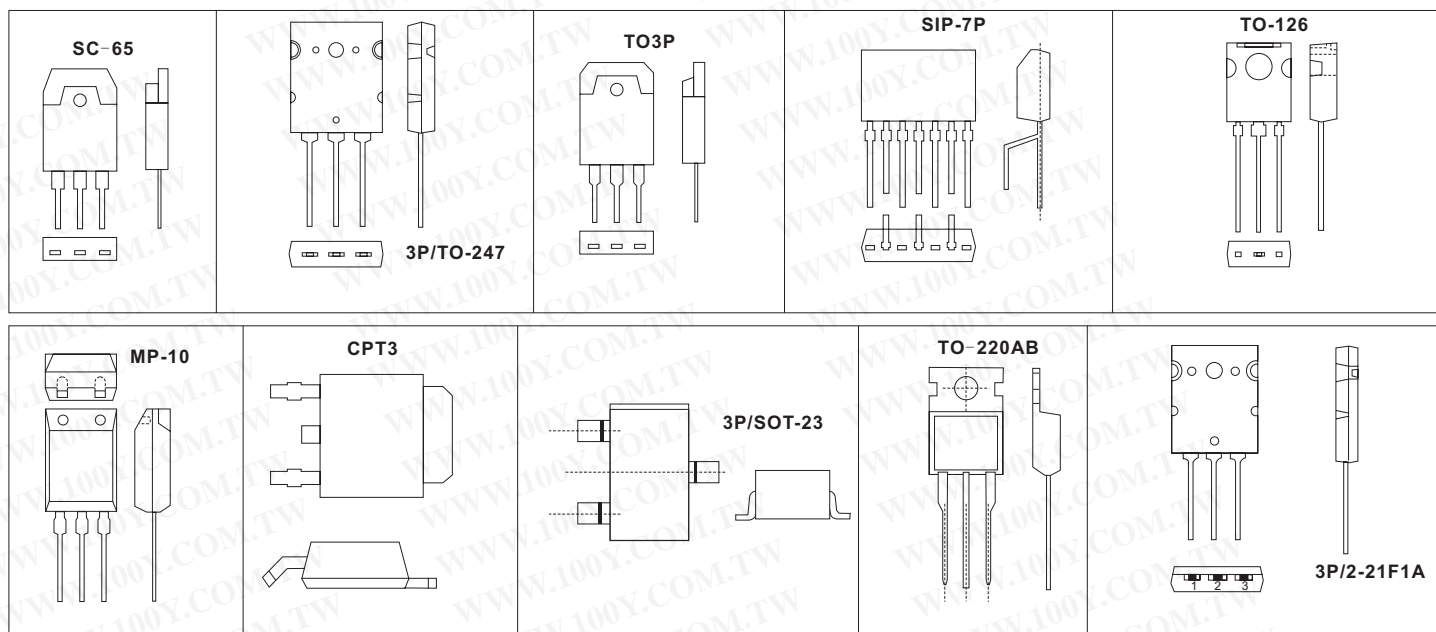


二极管+电晶体+模块

2SA~系列电晶体

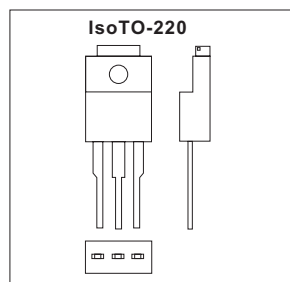
详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Pol	Ic(max)	Pc(max)	Vceo(max)	hfe(min.-max.)	Pins/Package
3890	2SA1102		PNP planar silicon transistor. Audio power amplifier DC to DC converter.	PNP	-6A	60W	-80V		3P/TO-3PN
5831	2SA1516		2SA 系列电晶体	P	-12A	130W	-180V	55-180	3P/TO-3PN
35818	2SA1302	MOSPEC	POWER TRANSISTORS	PNP	15A	150W	200V	55-160	3P/TO-247
5832	2SA1553	TOSHIBA	High-power PNP silicon power transistor	PNP	-15A	150W	-230V	55-160	3P/TO-247
41137	2SA1303	SanKen	Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC3284)	PNP	-14A	125W	-150V	50min	3P/TO-3
36797	2SA1693	SanKen	Silicon PNP Epitaxial Planar Transistor(Audio and General Purpose)	PNP	-6A	60W	-80V	50min	3P/TO-3
40112	2SA1694	SANYO	Silicon PNP Epitaxial Planar Transistor	PNP	-8A	80W	-120V	VCE=-4V, IC=-3A	TO-3
36801	2SA1695	SanKen	Silicon PNP Epitaxial Planar Transistor(Audio and General Purpose)	PNP	-10A	100W	-140V	50min	3P/TO-3
38709	2SA1988	NEC	PNP SILICON TRANSISTOR POWER AMPLIFIER INDUSTRIAL USE	PNP	-7A		-200V		TO-3P
18004	2SA5207A	HITACHI	NPN Triple Diffused Planar	NPN	10A	50W	800V	4-7V	3P/TO
41138	2SC3284	SanKen	Silicon NPN Epitaxial Planar Transistor (Complement to type 2SA1303)	NPN	14A	125W	150V	50min	3P/TO-3
42026	2SA1349	TOSHIBA	TOSHIBA_2SA~系列电晶体	PNP	-100mA	400mW	-80V	0.9-1.0	SIP-7P
36442	2SA1357	TOSHIBA	TRANSISTOR (STROBE FLASH, AUDIO POWER AMPLIFIER APPLICATIONS)	PNP	-5A	10W	-20V	100-320	TO-126
3892	2SA1358	TOSHIBA	Silicon PNP transistor for audio frequency power amplifier applications	PNP	-1A	1.5W	-120V	80-240	3P/TO-126
38939	2SA1546	NEC	PNP SILICON POWER TRANSISTOR	PNP	-0.1A		-250V		TO-126
38731	2SA1714	NEC	PNP SILICON EPITAXIAL POWER TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING	PNP	-3A		-100V		TO-126
5956	2SA715	HITACHI	Bipolar power general purpose transistor	PNP	-2.5A	0.75W	-35V	60-320	3P/TO-126
38737	2SA1840	NEC	PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING	PNP	-5A		-100V		MP-10
38738	2SA1841	NEC	PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING	PNP	-8A		-100V		MP-10
35825	2SA1952	ROHM	High-speed Switching Transistor	PNP	-5A	1W	-60V	120-270	CPT3
18446	2SA1943-0	TOSHIBA	Power Amp. Application	PNP	-15A	150W	-230V	55-160	3P/2-21F1A
22167	2SA812M6TB-A	NEC	PNP EPITAXIAL SILICON TRANSISTOR	PNP	-100mA	150mW	-50V	90-600	3P/SOT-23
35826	2SA968	TOSHIBA	SILICON PNP EPITAXIAL TRANSISTOR	PNP	-1.5A	25W	-160V	70-240	TO-220AB

2SB~系列电晶体

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100Y 编号	厂商编号	制造厂商	说明	Pol	Ic(max)	Vceo(max)	Pins/Package
38708	2SB1094	NEC	PNP SILICON EPITAXIAL TRANSISTOR	PNP	-3A	-60V	IsoTO-220
38755	2SB1430	NEC	PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING	PNP	-5A	-100V	IsoTO-220
38756	2SB1431	NEC	PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING	PNP	8A	-100V	IsoTO-220
38757	2SB1432	NEC	PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING	PNP	-10A	-100V	IsoTO-220

